15 MHz Rail-to-Rail Operational Amplifiers

ANALOG DEVICES

Data Sheet

OP162/OP262/OP462

FEATURES

Wide bandwidth: 15 MHz
Low offset voltage: 325 µV max
Low noise: 9.5 nV/√Hz @ 1 kHz
Single-supply operation: 2.7 V to 12 V
Rail-to-rail output swing
Low TCV$_{OS}$: 1 µV/°C typ
High slew rate: 13 V/µs
No phase inversion
Unity-gain stable

APPLICATIONS

Portable instrumentation
Sampling ADC amplifier
Wireless LANs
Direct access arrangement
Office automation

GENERAL DESCRIPTION

The OP162 (single), OP262 (dual), and OP462 (quad) rail-to-rail 15 MHz amplifiers feature the extra speed new designs require, with the benefits of precision and low power operation. With their incredibly low offset voltage of 45 µV (typical) and low noise, they are perfectly suited for precision filter applications and instrumentation. The low supply current of 500 µA (typical) is critical for portable or densely packed designs. In addition, the rail-to-rail output swing provides greater dynamic range and control than standard video amplifiers.

These products operate from single supplies as low as 2.7 V to dual supplies of ±6 V. The fast settling times and wide output swings recommend them for buffers to sampling A/D converters. The output drive of 30 mA (sink and source) is needed for many audio and display applications; more output current can be supplied for limited durations. The OPx62 family is specified over the extended industrial temperature range (−40°C to +125°C). The single OP162 amplifiers are available in 8-lead SOIC package. The dual OP262 amplifiers are available in 8-lead SOIC and TSSOP packages. The quad OP462 amplifiers are available in 14-lead, narrow-body SOIC and TSSOP packages.
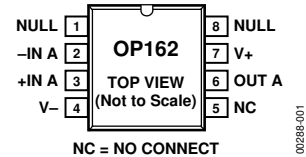
PIN CONFIGURATIONS
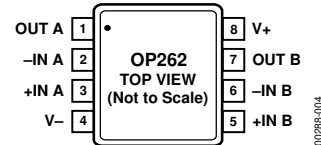

Figure 1. 8-Lead Narrow-Body SOIC (S Suffix)

Figure 2. 8-Lead TSSOP (RU Suffix) and 8-Lead Narrow-Body SOIC (S Suffix)
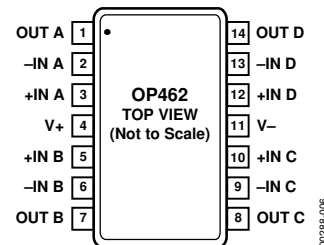

Figure 3. 14-Lead Narrow-Body SOIC (S Suffix) and 14-Lead TSSOP (RU Suffix)

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REVISION HISTORY

SPECIFICATIONS

@ V_S = 5.0 V, V_{CM} = 0 V, T_A = 25°C, unless otherwise noted.

Table 1. Electrical Characteristics

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
INPUT CHARACTERISTICS						
Offset Voltage	V_{OS}	OP162G, OP262G, OP462G		45	325	µV
		−40°C ≤ T_A ≤ +125°C			800	µV
		H grade, −40°C ≤ T_A ≤ +125°C			1	mV
		D grade		0.8	3	mV
		−40°C ≤ T_A ≤ +125°C			5	mV
Input Bias Current	I_B			360	600	nA
		−40°C ≤ T_A ≤ +125°C			650	nA
Input Offset Current	I_{OS}			±2.5	±25	nA
		−40°C ≤ T_A ≤ +125°C			±40	nA
Input Voltage Range	V_{CM}		0		4	V
Common-Mode Rejection	CMRR	0 V ≤ V_{CM} ≤ 4.0 V, −40°C ≤ T_A ≤ +125°C	70	110		dB
Large Signal Voltage Gain	A_{VO}	R_L = 2 kΩ, 0.5 ≤ V_{OUT} ≤ 4.5 V		30		V/mV
		R_L = 10 kΩ, 0.5 ≤ V_{OUT} ≤ 4.5 V	65	88		V/mV
		R_L = 10 kΩ, −40°C ≤ T_A ≤ +125°C	40			V/mV
Long-Term Offset Voltage[1]	V_{OS}	G grade			600	µV
Offset Voltage Drift[2]	$\Delta V_{OS}/\Delta T$			1		µV/°C
Bias Current Drift	$\Delta I_B/\Delta T$			250		pA/°C
OUTPUT CHARACTERISTICS						
Output Voltage Swing High	V_{OH}	I_L = 250 µA, −40°C ≤ T_A ≤ +125°C	4.95	4.99		V
		I_L = 5 mA	4.85	4.94		V
Output Voltage Swing Low	V_{OL}	I_L = 250 µA, −40°C ≤T_A ≤ +125°C		14	50	mV
		I_L = 5 mA		65	150	mV
Short-Circuit Current	I_{SC}	Short to ground		±80		mA
Maximum Output Current	I_{OUT}			±30		mA
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	V_S = 2.7 V to 7 V		120		dB
		−40°C ≤ T_A ≤ +125°C	90			dB
Supply Current/Amplifier	I_{SY}	OP162, V_{OUT} = 2.5 V		600	750	µA
		−40°C ≤ T_A ≤ +125°C			1	mA
		OP262, OP462, V_{OUT} = 2.5 V		500	700	µA
		−40°C ≤ T_A ≤ +125°C			850	µA
DYNAMIC PERFORMANCE						
Slew Rate	SR	1 V < V_{OUT} < 4 V, R_L = 10 kΩ		10		V/µs
Settling Time	t_S	To 0.1%, A_V = −1, V_O = 2 V step		540		ns
Gain Bandwidth Product	GBP			15		MHz
Phase Margin	φ_m			61		Degrees
NOISE PERFORMANCE						
Voltage Noise	e_n p-p	0.1 Hz to 10 Hz		0.5		µV p-p
Voltage Noise Density	e_n	f = 1 kHz		9.5		nV/$\sqrt{Hz}$
Current Noise Density	i_n	f = 1 kHz		0.4		pA/$\sqrt{Hz}$

[1] Long-term offset voltage is guaranteed by a 1000 hour life test performed on three independent lots at 125°C, with an LTPD of 1.3.
[2] Offset voltage drift is the average of the −40°C to +25°C delta and the +25°C to +125°C delta.

@ V_S = 3.0 V, V_{CM} = 0 V, T_A = 25°C, unless otherwise noted.

Table 2. Electrical Characteristics

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
INPUT CHARACTERISTICS						
Offset Voltage	V_{OS}	OP162G, OP262G, OP462G		50	325	µV
		G, H grades, −40°C ≤ T_A ≤ +125°C			1	mV
		D grade		0.8	3	mV
		−40°C ≤ T_A ≤ +125°C			5	mV
Input Bias Current	I_B			360	600	nA
Input Offset Current	I_{OS}			±2.5	±25	nA
Input Voltage Range	V_{CM}		0		2	V
Common-Mode Rejection	CMRR	0 V ≤ V_{CM} ≤ 2.0 V, −40°C ≤ T_A ≤ +125°C	70	110		dB
Large Signal Voltage Gain	A_{VO}	R_L = 2 kΩ, 0.5 V ≤ V_{OUT} ≤ 2.5 V		20		V/mV
		R_L = 10 kΩ, 0.5 V ≤ V_{OUT} ≤ 2.5 V	20	30		V/mV
Long-Term Offset Voltage[1]	V_{OS}	G grade			600	µV
OUTPUT CHARACTERISTICS						
Output Voltage Swing High	V_{OH}	I_L = 250 µA	2.95	2.99		V
		I_L = 5 mA	2.85	2.93		V
Output Voltage Swing Low	V_{OL}	I_L = 250 µA		14	50	mV
		I_L = 5 mA		66	150	mV
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	V_S = 2.7 V to 7 V, −40°C ≤ T_A ≤ +125°C	60	110		dB
Supply Current/Amplifier	I_{SY}	OP162, V_{OUT} = 1.5 V		600	700	µA
		−40°C ≤ T_A ≤ +125°C			1	mA
		OP262, OP462, V_{OUT} = 1.5 V		500	650	µA
		−40°C ≤ T_A ≤ +125°C			850	µA
DYNAMIC PERFORMANCE						
Slew Rate	SR	R_L = 10 kΩ		10		V/µs
Settling Time	t_S	To 0.1%, A_V = −1, V_O = 2 V step		575		ns
Gain Bandwidth Product	GBP			15		MHz
Phase Margin	φ_m			59		Degrees
NOISE PERFORMANCE						
Voltage Noise	e_n p-p	0.1 Hz to 10 Hz		0.5		µV p-p
Voltage Noise Density	e_n	f = 1 kHz		9.5		nV/$\sqrt{Hz}$
Current Noise Density	i_n	f = 1 kHz		0.4		pA/$\sqrt{Hz}$

[1] Long-term offset voltage is guaranteed by a 1000 hour life test performed on three independent lots at 125°C, with an LTPD of 1.3.

@ V_S = ±5.0 V, V_{CM} = 0 V, T_A = 25°C, unless otherwise noted.

Table 3. Electrical Characteristics

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
INPUT CHARACTERISTICS						
Offset Voltage	V_{OS}	OP162G, OP262G, OP462G		25	325	µV
		−40°C ≤ T_A ≤ +125°C			800	µV
		H grade, −40°C ≤ T_A ≤ +125°C			1	mV
		D grade		0.8	3	mV
		−40°C ≤ T_A ≤ +125°C			5	mV
Input Bias Current	I_B			260	500	nA
		−40°C ≤ T_A ≤ +125°C			650	nA
Input Offset Current	I_{OS}			±2.5	±25	nA
		−40°C ≤ T_A ≤ +125°C			±40	nA
Input Voltage Range	V_{CM}		−5		+4	V
Common-Mode Rejection	CMRR	−4.9 V ≤ V_{CM} ≤ +4.0 V, −40°C ≤ T_A ≤ +125°C	70	110		dB
Large Signal Voltage Gain	A_{VO}	R_L = 2 kΩ, −4.5 V ≤ V_{OUT} ≤ +4.5 V		35		V/mV
		R_L = 10 kΩ, −4.5 V ≤ V_{OUT} ≤ +4.5 V	75	120		V/mV
		−40°C ≤ T_A ≤ +125°C	25			V/mV
Long-Term Offset Voltage[1]	V_{OS}	G grade			600	µV
Offset Voltage Drift[2]	$\Delta V_{OS}/\Delta T$			1		µV/°C
Bias Current Drift	$\Delta I_B/\Delta T$			250		pA/°C
OUTPUT CHARACTERISTICS						
Output Voltage Swing High	V_{OH}	I_L = 250 µA, −40°C ≤ T_A ≤ +125°C	4.95	4.99		V
		I_L = 5 mA	4.85	4.94		V
Output Voltage Swing Low	V_{OL}	I_L = 250 µA, −40°C ≤ T_A ≤ +125°C		−4.99	−4.95	V
		I_L = 5 mA		−4.94	−4.85	V
Short-Circuit Current	I_{SC}	Short to ground		±80		mA
Maximum Output Current	I_{OUT}			±30		mA
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	V_S = ±1.35 V to ±6 V,				
		−40°C ≤ T_A ≤ +125°C	60	110		dB
Supply Current/Amplifier	I_{SY}	OP162, V_{OUT} = 0 V		650	800	µA
		−40°C ≤ T_A ≤ +125°C			1.15	mA
		OP262, OP462, V_{OUT} = 0 V		550	775	µA
		−40°C ≤ T_A ≤ +125°C			1	mA
Supply Voltage Range	V_S		3.0 (±1.5)		12 (±6)	V
DYNAMIC PERFORMANCE						
Slew Rate	SR	−4 V < V_{OUT} < 4 V, R_L = 10 kΩ		13		V/µs
Settling Time	t_S	To 0.1%, A_V = −1, V_O = 2 V step		475		ns
Gain Bandwidth Product	GBP			15		MHz
Phase Margin	φ_m			64		Degrees
NOISE PERFORMANCE						
Voltage Noise	e_n p-p	0.1 Hz to 10 Hz		0.5		µV p-p
Voltage Noise Density	e_n	f = 1 kHz		9.5		nV/√Hz
Current Noise Density	i_n	f = 1 kHz		0.4		pA/√Hz

[1] Long-term offset voltage is guaranteed by a 1000 hour life test performed on three independent lots at +125°C, with an LTPD of 1.3.
[2] Offset voltage drift is the average of the −40°C to +25°C delta and the +25°C to +125°C delta.

ABSOLUTE MAXIMUM RATINGS

Table 4.

Parameter	Min
Supply Voltage	±6 V
Input Voltage[1]	±6 V
Differential Input Voltage[2]	±0.6 V
Internal Power Dissipation	
SOIC (S)	Observe Derating Curves
TSSOP (RU)	Observe Derating Curves
Output Short-Circuit Duration	Observe Derating Curves
Storage Temperature Range	−65°C to +150°C
Operating Temperature Range	−40°C to +125°C
Junction Temperature Range	−65°C to +150°C
Lead Temperature Range (Soldering, 10 sec)	300°C

[1] For supply voltages greater than 6 V, the input voltage is limited to less than or equal to the supply voltage.

[2] For differential input voltages greater than 0.6 V, the input current should be limited to less than 5 mA to prevent degradation or destruction of the input devices.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Table 5.

Package Type	θ_{JA}[1]	θ_{JC}	Unit
8-Lead SOIC (S)	157	56	°C/W
8-Lead TSSOP (RU)	208		°C/W
14-Lead SOIC (S)	105		°C/W
14-Lead TSSOP (RU)	148		°C/W

[1] θ_{JA} is specified for the worst-case conditions, that is, θ_{JA} is specified for a device soldered in circuit board for SOIC, and TSSOP packages.

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.
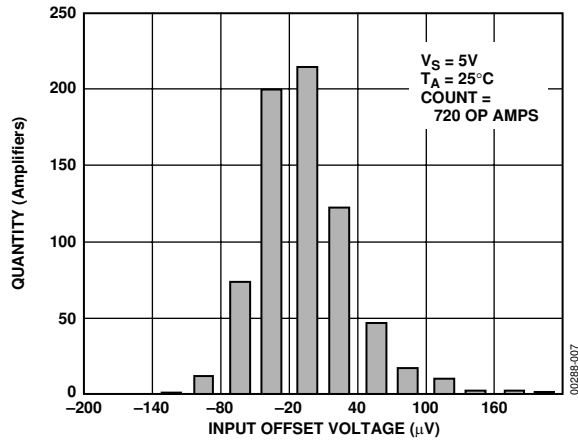
TYPICAL PERFORMANCE CHARACTERISTICS

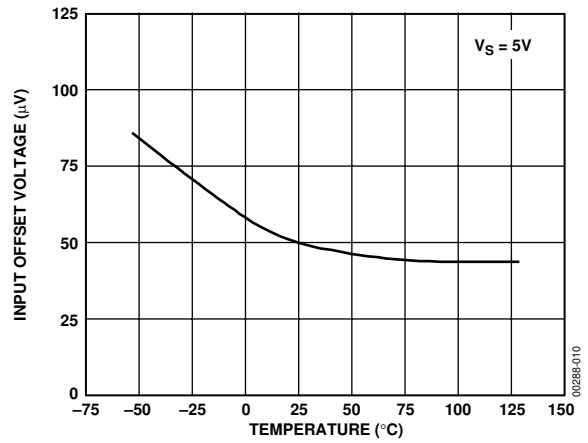Figure 4. OP462 Input Offset Voltage Distribution
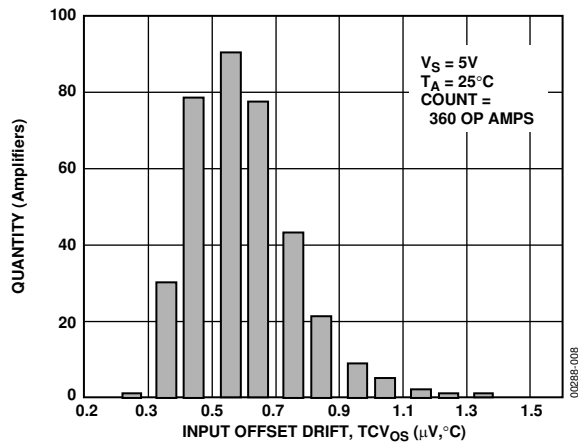

Figure 5. OP462 Input Offset Voltage Drift (TCV$_{OS}$)

Figure 6. OP462 Input Bias Current vs. Common-Mode Voltage
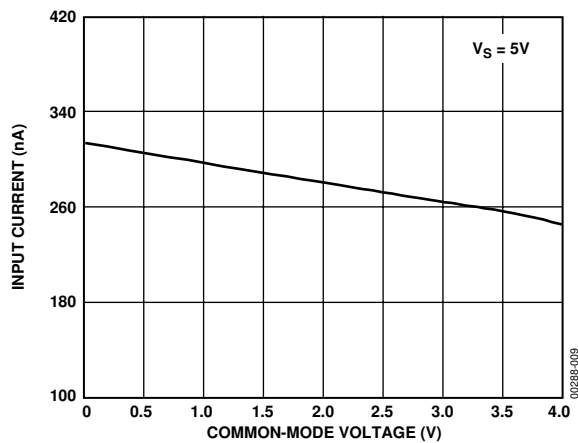

Figure 7. OP462 Input Offset Voltage vs. Temperature
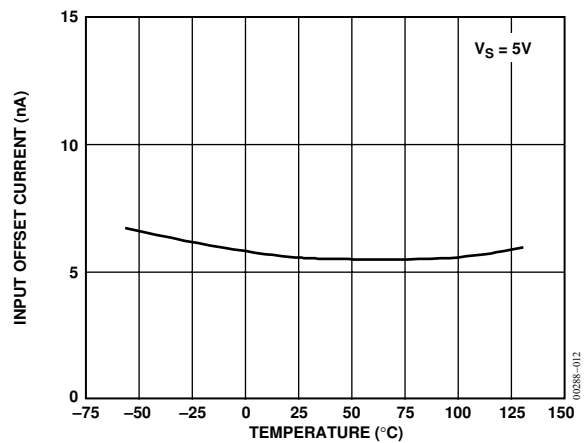

Figure 8. OP462 Input Bias Current vs. Temperature

Figure 9. OP462 Input Offset Current vs. Temperature
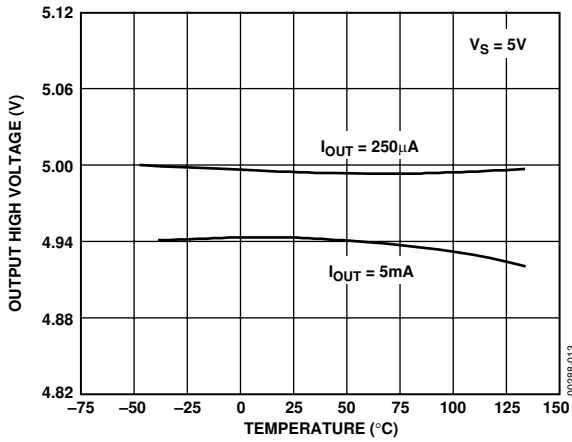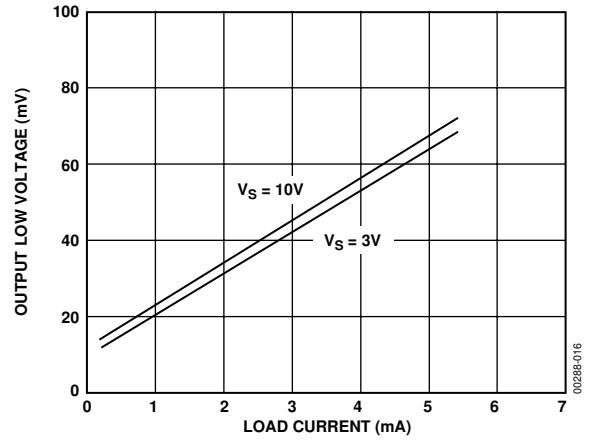
Figure 10. OP462 Output High Voltage vs. Temperature
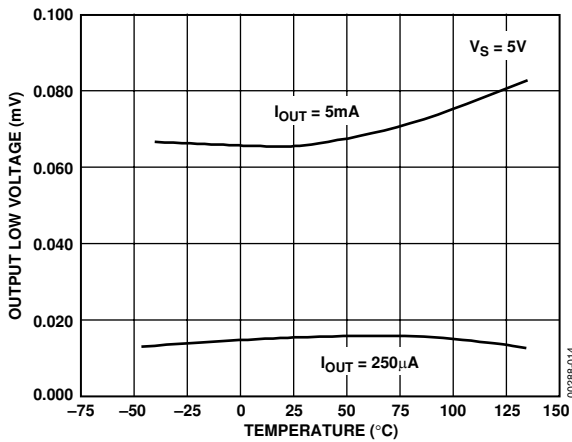

Figure 11. OP462 Output Low Voltage vs. Temperature

Figure 12. OP462 Open-Loop Gain vs. Temperature

Figure 13. Output Low Voltage to Supply Rail vs. Load Current
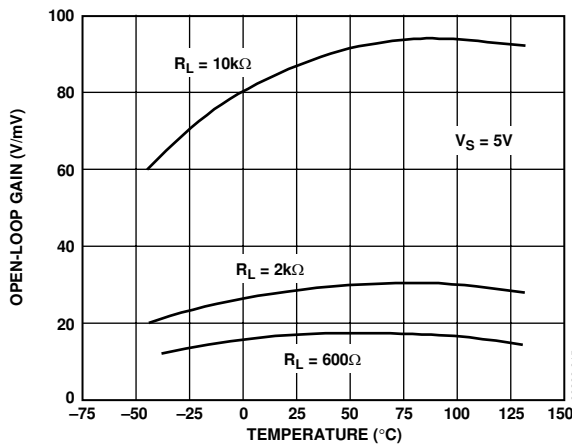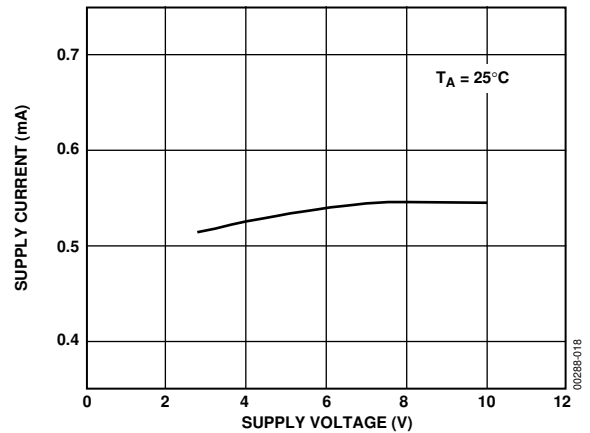

Figure 14. Supply Current/Amplifier vs. Temperature

Figure 15. OP462 Supply Current/Amplifier vs. Supply Voltage
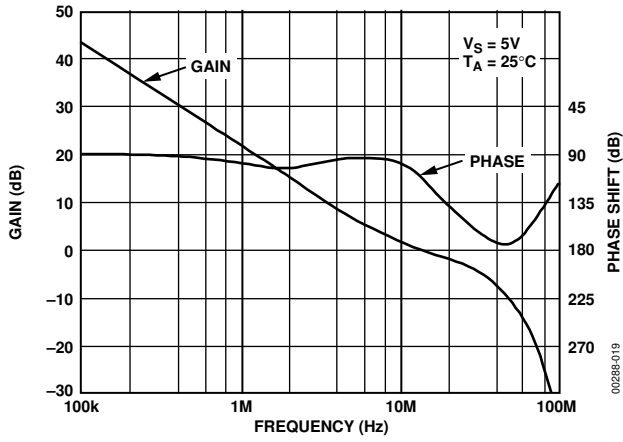
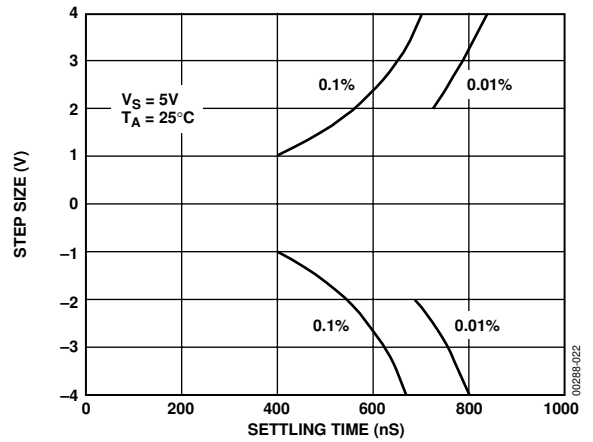Figure 16. Open-Loop Gain and Phase vs. Frequency (No Load)
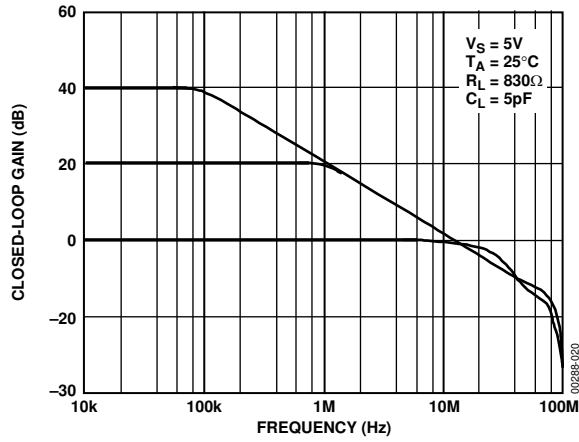

Figure 17. Closed-Loop Gain vs. Frequency

Figure 18. Maximum Output Swing vs. Frequency

Figure 19. Step Size vs. Settling Time

Figure 20. Small-Signal Overshoot vs. Capacitance

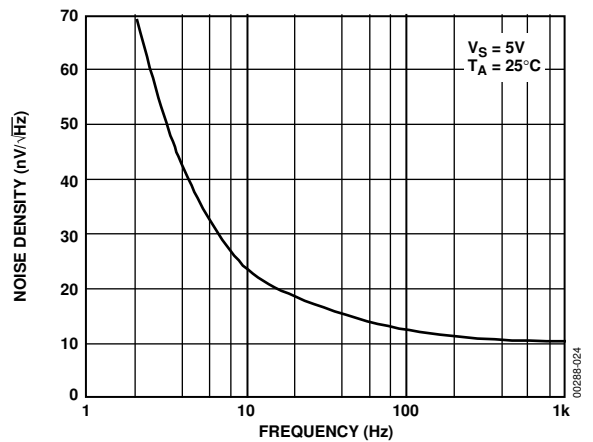Figure 21. Voltage Noise Density vs. Frequency
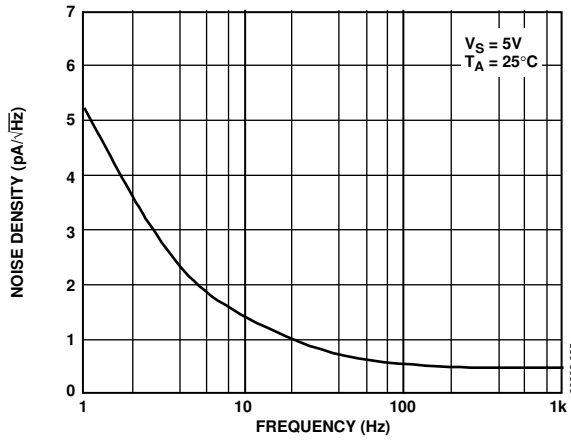
Figure 22. Current Noise Density vs. Frequency
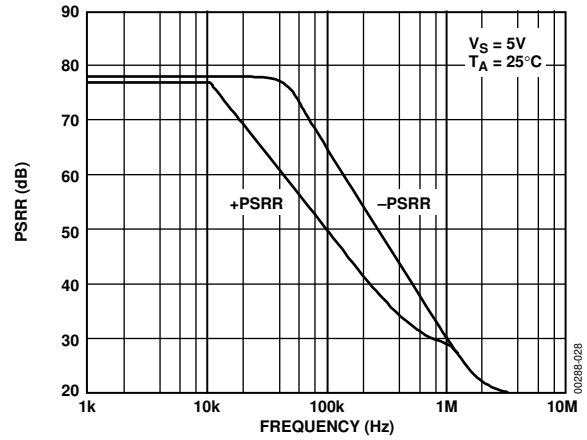

Figure 23. Output Impedance vs. Frequency

Figure 24. CMRR vs. Frequency

Figure 25. PSRR vs. Frequency

Figure 26. 0.1 Hz to 10 Hz Noise
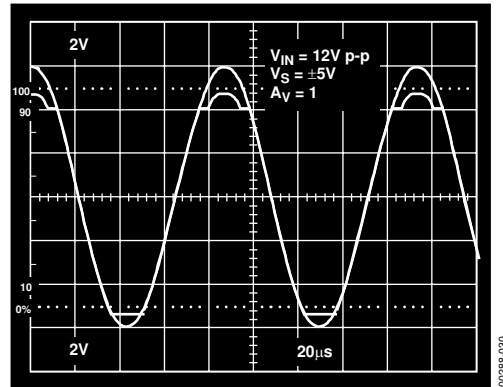

Figure 27. No Phase Reversal (V_{IN} = 12 V p-p, V_S = ±5 V, A_V = 1)
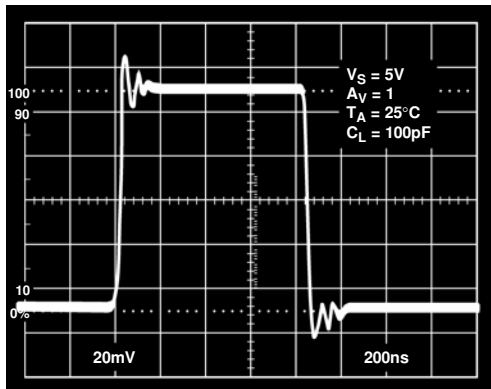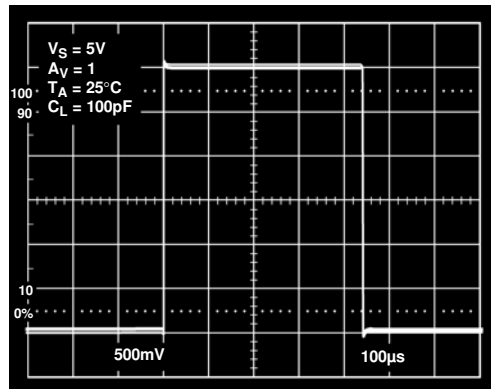
Figure 28. Small Signal Transient Response

Figure 29. Large Signal Transient Response

APPLICATIONS

FUNCTIONAL DESCRIPTION

The OPx62 family is fabricated using Analog Devices' high speed complementary bipolar process, also called XFCB. This process trench isolates each transistor to lower parasitic capacitances for high speed performance. This high speed process has been implemented without sacrificing the excellent transistor matching and overall dc performance characteristic of Analog Devices' complementary bipolar process. This makes the OPx62 family an excellent choice as an extremely fast and accurate low voltage op amp.

Figure 30 shows a simplified equivalent schematic for the OP162. A PNP differential pair is used at the input of the device. The cross connecting of the emitters lowers the transconductance of the input stage improving the slew rate of the device. Lowering the transconductance through cross connecting the emitters has another advantage in that it provides a lower noise factor than if emitter degeneration resistors were used. The input stage can function with the base voltages taken all the way to the negative power supply, or up to within 1 V of the positive power supply.
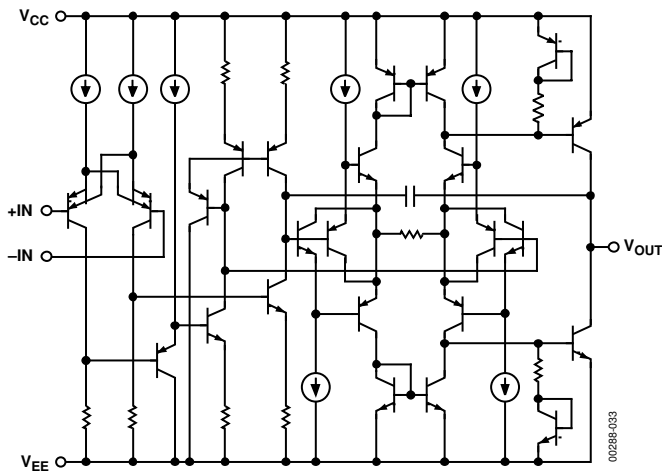

Figure 30. Simplified Schematic

Two complementary transistors in a common-emitter configuration are used for the output stage. This allows the output of the device to swing to within 50 mV of either supply rail at load currents less than 1 mA. As load current increases, the maximum voltage swing of the output decreases. This is due to the collector-to-emitter saturation voltages of the output transistors increasing. The gain of the output stage, and consequently the open-loop gain of the amplifier, is dependent on the load resistance connected at the output. Because the dominant pole frequency is inversely proportional to the open-loop gain, the unity-gain bandwidth of the device is not affected by the load resistance. This is typically the case in rail-to-rail output devices.

OFFSET ADJUSTMENT

Because the OP162/OP262/OP462 have an exceptionally low typical offset voltage, adjustment to correct offset voltage may not be needed. However, the OP162 has pinouts to attach a nulling resistor. Figure 31 shows how the OP162 offset voltage can be adjusted by connecting a potentiometer between Pin 1 and Pin 8, and connecting the wiper to V_{CC}. It is important to avoid accidentally connecting the wiper to V_{EE}, as this can damage the device. The recommended value for the potentiometer is 20 kΩ.
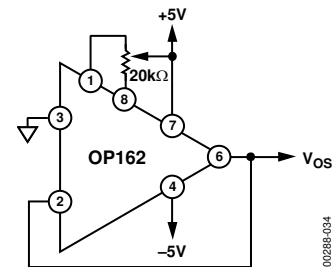

Figure 31. Offset Adjustment Schematic

RAIL-TO-RAIL OUTPUT

The OP162/OP262/OP462 have a wide output voltage range that extends to within 60 mV of each supply rail with a load current of 5 mA. Decreasing the load current extends the output voltage range even closer to the supply rails. The common-mode input range extends from ground to within 1 V of the positive supply. It is recommended that there be some minimal amount of gain when a rail-to-rail output swing is desired. The minimum gain required is based on the supply voltage and can be found as

$$A_{V,min} = \frac{V_S}{V_S - 1}$$

where V_S is the positive supply voltage. With a single-supply voltage of 5 V, the minimum gain to achieve rail-to-rail output should be 1.25.

OUTPUT SHORT-CIRCUIT PROTECTION

To achieve a wide bandwidth and high slew rate, the output of the OP162/OP262/OP462 are not short-circuit protected. Shorting the output directly to ground or to a supply rail may destroy the device. The typical maximum safe output current is ±30 mA. Steps should be taken to ensure the output of the device will not be forced to source or sink more than 30 mA.

In applications where some output current protection is needed, but not at the expense of reduced output voltage headroom, a low value resistor in series with the output can be used. This is shown in Figure 32. The resistor is connected within the feedback loop of the amplifier so that if V_OUT is shorted to ground

and V_{IN} swings up to 5 V, the output current will not exceed 30 mA. For single 5 V supply applications, resistors less than 169 Ω are not recommended.
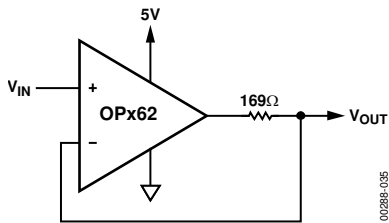

Figure 32. Output Short-Circuit Protection

INPUT OVERVOLTAGE PROTECTION

The input voltage should be limited to ±6 V, or damage to the device can occur. Electrostatic protection diodes placed in the input stage of the device help protect the amplifier from static discharge. Diodes are connected between each input as well as from each input to both supply pins as shown in the simplified equivalent circuit in Figure 30. If an input voltage exceeds either supply voltage by more than 0.6 V, or if the differential input voltage is greater than 0.6 V, these diodes energize causing overvoltage damage.

The input current should be limited to less than 5 mA to prevent degradation or destruction of the device by placing an external resistor in series with the input at risk of being overdriven. The size of the resistor can be calculated by dividing the maximum input voltage by 5 mA. For example, if the differential input voltage could reach 5 V, the external resistor should be 5 V/5 mA = 1 kΩ. In practice, this resistor should be placed in series with both inputs to balance any offset voltages created by the input bias current.

OUTPUT PHASE REVERSAL

The OP162/OP262/OP462 are immune to phase reversal as long as the input voltage is limited to ±6 V. Figure 27 shows the output of a device with the input voltage driven beyond the supply voltages. Although the device's output does not change phase, large currents due to input overvoltage could result, damaging the device. In applications where the possibility of an input voltage exceeding the supply voltage exists, overvoltage protection should be used, as described in the previous section.

POWER DISSIPATION

The maximum power that can be safely dissipated by the OP162/OP262/OP462 is limited by the associated rise in junction temperature. The maximum safe junction temperature is 150°C; device performance suffers when this limit is exceeded. If this maximum is only momentarily exceeded, proper circuit operation will be restored as soon as the die temperature is reduced. Leaving the device in an "overheated" condition for an extended period can result in permanent damage to the device.

To calculate the internal junction temperature of the OPx62, use the formula

$$T_J = P_{DISS} \times \theta_{JA} + T_A$$

where:
T_J is the OPx62 junction temperature.
P_{DISS} is the OPx62 power dissipation.
θ_{JA} is the OPx62 package thermal resistance, junction-to-ambient temperature.
T_A is the ambient temperature of the circuit.

The power dissipated by the device can be calculated as

$$P_{DISS} = I_{LOAD} \times (V_S - V_{OUT})$$

where:
I_{LOAD} is the OPx62 output load current.
V_S is the OPx62 supply voltage.
V_{OUT} is the OPx62 output voltage.

Figure 33 and Figure 34 provide a convenient way to determine if the device is being overheated. The maximum safe power dissipation can be found graphically, based on the package type and the ambient temperature around the package. By using the previous equation, it is a simple matter to see if P_{DISS} exceeds the device's power derating curve. To ensure proper operation, it is important to observe the recommended derating curves shown in Figure 33 and Figure 34.
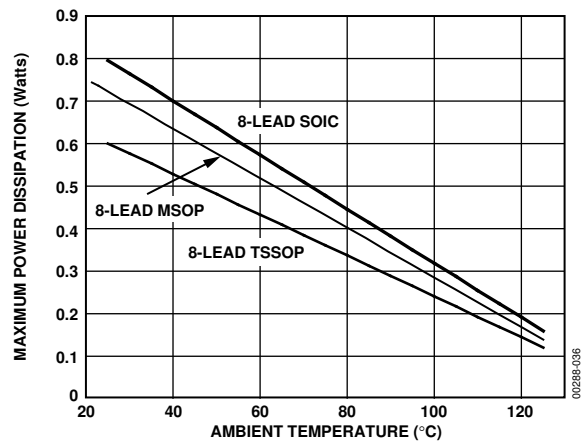

Figure 33. Maximum Power Dissipation vs. Temperature for 8-Lead Package Types
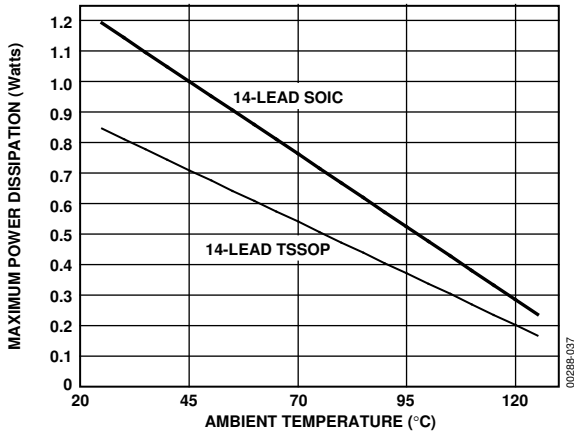
Figure 34. Maximum Power Dissipation vs. Temperature for
14-Lead Package Types

UNUSED AMPLIFIERS

It is recommended that any unused amplifiers in a dual or a
quad package be configured as a unity-gain follower with a
1 kΩ feedback resistor connected from the inverting input to
the output, and the noninverting input tied to the ground plane.

POWER-ON SETTLING TIME

The time it takes for the output of an op amp to settle after a
supply voltage is delivered can be an important consideration in
some power-up-sensitive applications. An example of this
would be in an A/D converter where the time until valid data
can be produced after power-up is important.

The OPx62 family has a rapid settling time after power-up.
Figure 35 shows the OP462 output settling times for a single-
supply voltage of V_S = +5 V. The test circuit in Figure 36 was
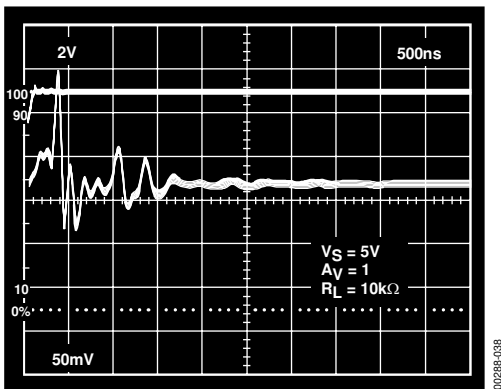used to find the power-on settling times for the device.

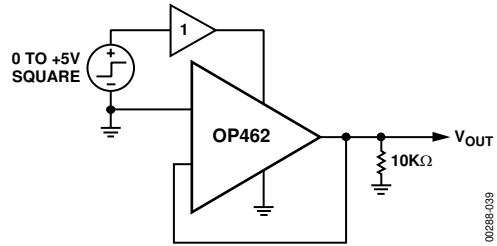Figure 35. Oscilloscope Photo of V_S and V_{OUT}

Figure 36. Test Circuit for Power-On Settling Time

CAPACITIVE LOAD DRIVE

The OP162/OP262/OP462 are high speed, extremely accurate
devices that tolerate some capacitive loading at their outputs. As
load capacitance increases, unity-gain bandwidth of an OPx62
device decreases. This also causes an increase in overshoot and
settling time for the output. Figure 38 shows an example of this
with the device configured for unity gain and driving a 10 kΩ
resistor and 300 pF capacitor placed in parallel.

By connecting a series R-C network, commonly called a
"snubber" network, from the output of the device to ground,
this ringing can be eliminated and overshoot can be
significantly reduced. Figure 37 shows how to set up the
snubber network, and Figure 39 shows the improvement in
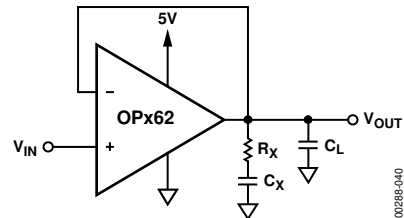output response with the network added.

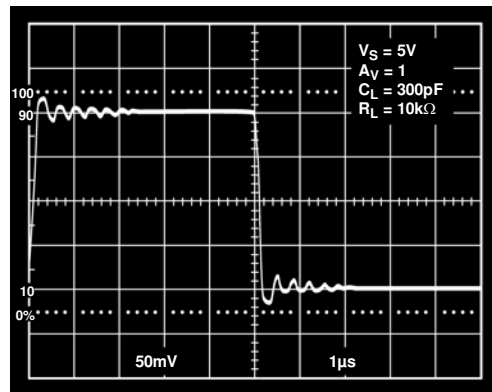Figure 37. Snubber Network Compensation for Capacitive Loads

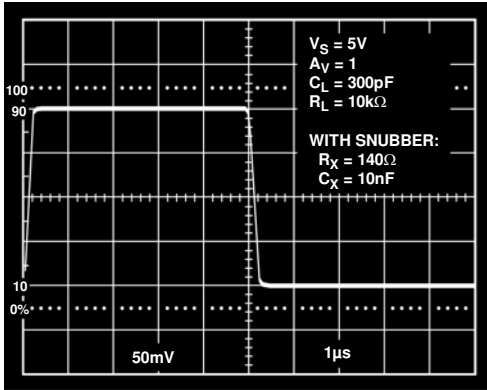Figure 38. A Photo of a Ringing Square Wave

Figure 39. A Photo of a Nice Square Wave at the Output

The network operates in parallel with the load capacitor, C_L, and provides compensation for the added phase lag. The actual values of the network resistor and capacitor are empirically determined to minimize overshoot and maximize unity-gain bandwidth. Table 6 shows a few sample snubber networks for large load capacitors.

Table 6. Snubber Networks for Large Capacitive Loads

C_{LOAD}	R_X	C_X
< 300 pF	140 Ω	10 nF
500 pF	100 Ω	10 nF
1 nF	80 Ω	10 nF
10 nF	10 Ω	47 nF

Higher load capacitance will reduce the unity-gain bandwidth of the device. Figure 40 shows unity-gain bandwidth vs. capacitive load. The snubber network does not provide any increase in bandwidth, but it substantially reduces ringing and overshoot, as shown between Figure 38 and Figure 39.
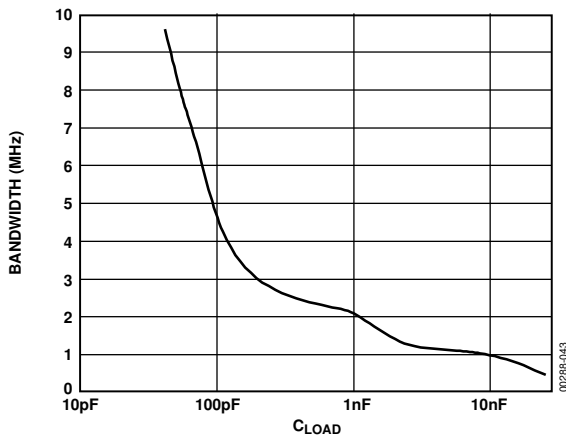

Figure 40. Unity-Gain Bandwidth vs. C_{LOAD}

TOTAL HARMONIC DISTORTION AND CROSSTALK

The OPx62 device family offers low total harmonic distortion making it an excellent choice for audio applications. Figure 41 shows a graph of THD plus noise figures at 0.001% for the OP462.

Figure 42 shows the worst case crosstalk between two amplifiers in the OP462. A 1 V rms signal is applied to one amplifier while measuring the output of an adjacent amplifier. Both amplifiers are configured for unity gain and supplied with ±2.5 V.
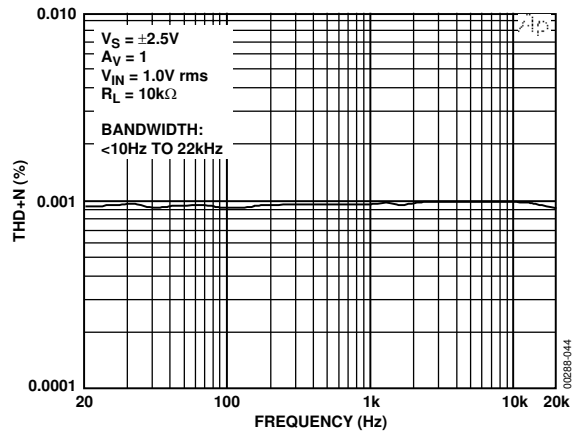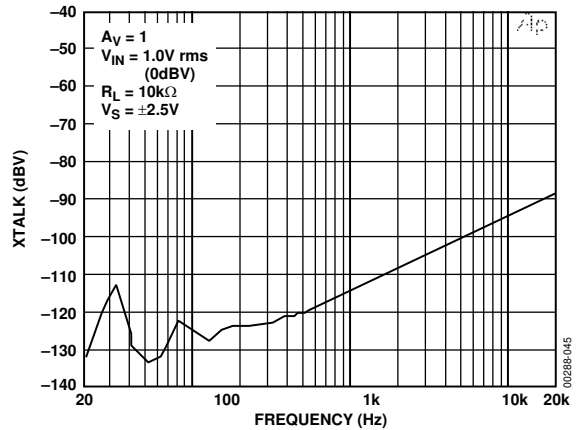

Figure 41. THD + N vs. Frequency

Figure 42. Crosstalk vs. Frequency

PCB LAYOUT CONSIDERATIONS

Because the OP162/OP262/OP462 can provide gains at high frequency, careful attention to board layout and component selection is recommended. As with any high speed application, a good ground plane is essential to achieve the optimum performance. This can significantly reduce the undesirable effects of ground loops and I × R losses by providing a low impedance reference point. Best results are obtained with a multilayer board design with one layer assigned to ground plane.

Use chip capacitors for supply bypassing, with one end of the capacitor connected to the ground plane and the other end connected within 1/8 inch of each power pin. An additional large tantalum electrolytic capacitor (4.7 µF to 10 µF) should be connected in parallel. This capacitor provides current for fast, large-signal changes at the device's output; therefore, it does not need to be placed as close to the supply pins.

APPLICATIONS CIRCUITS

SINGLE-SUPPLY STEREO HEADPHONE DRIVER

Figure 43 shows a stereo headphone output amplifier that can operate from a single 5 V supply. The reference voltage is derived by dividing the supply voltage down with two 100 kΩ resistors. A 10 μF capacitor prevents power supply noise from contaminating the audio signal and establishes an ac ground for the volume control potentiometers.

The audio signal is ac-coupled to each noninverting input through a 10 μF capacitor. The gain of the amplifier is controlled by the feedback resistors and is (R2/R1) + 1. For this example, the gain is 6. By removing R1, the amplifier would have unity gain. To short-circuit protect the output of the device, a 169 Ω resistor is placed at the output in the feedback network. This prevents any damage to the device if the headphone output becomes shorted. A 270 μF capacitor is used at the output to couple the amplifier to the headphone. This value is much larger than that used for the input because of the low impedance of headphones, which can range from 32 Ω to 600 Ω or more.
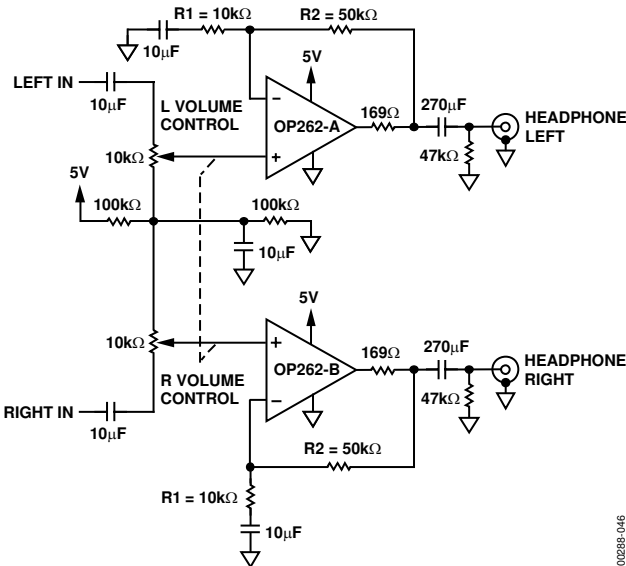

Figure 43. Headphone Output Amplifier

INSTRUMENTATION AMPLIFIER

Because of their high speed, low offset voltages, and low noise characteristics, the OP162/OP262/OP462 can be used in a wide variety of high speed applications, including precision instrumentation amplifiers. Figure 44 shows an example of such an application.
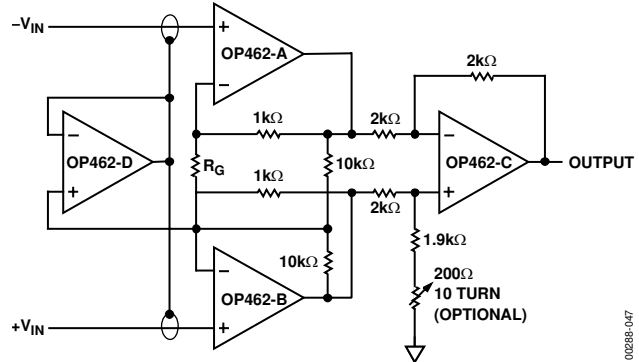

Figure 44. High Speed Instrumentation Amplifier

The differential gain of the circuit is determined by R_G, where

$$A_{DIFF} = 1 + \frac{2}{R_G}$$

with the R_G resistor value in kΩ. Removing R_G sets the circuit gain to unity.

The fourth op amp, OP462-D, is optional and is used to improve CMRR by reducing any input capacitance to the amplifier. By shielding the input signal leads and driving the shield with the common-mode voltage, input capacitance is eliminated at common-mode voltages. This voltage is derived from the midpoint of the outputs of OP462-A and OP462-B by using two 10 kΩ resistors followed by OP462-D as a unity-gain buffer.

It is important to use 1% or better tolerance components for the 2 kΩ resistors, as the common-mode rejection is dependent on their ratios being exact. A potentiometer should also be connected in series with the OP462-C noninverting input resistor to ground to optimize common-mode rejection.

The circuit in Figure 44 was implemented to test its settling time. The instrumentation amp was powered with −5 V, so the input step voltage went from −5 V to +4 V to keep the OP462 within its input range. Therefore, the 0.05% settling range is when the output is within 4.5 mV. Figure 45 shows the positive slope settling time to be 1.8 μs, and Figure 46 shows a settling time of 3.9 μs for the negative slope.
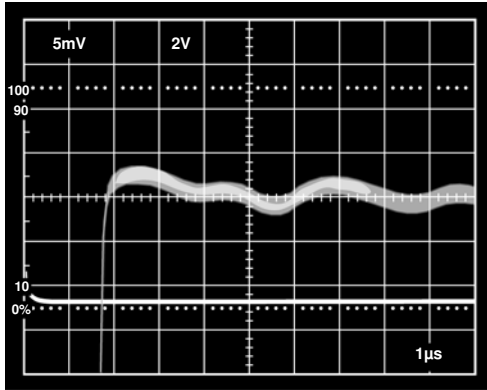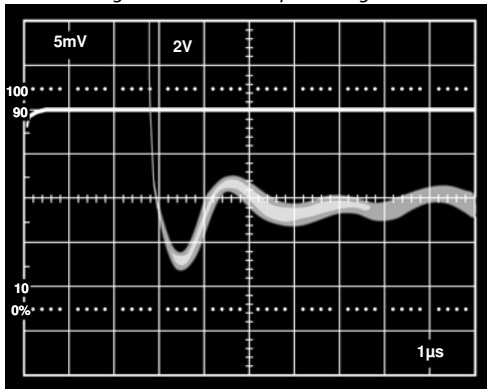
Figure 45. Positive Slope Settling Time

Figure 46. Negative Slope Settling Time

DIRECT ACCESS ARRANGEMENT

Figure 47 shows a schematic for a 5 V single-supply transmit/ receive telephone line interface for 600 Ω transmission systems. It allows full-duplex transmission of signals on a transformer-coupled 600 Ω line. Amplifier A1 provides gain that can be adjusted to meet the modem output drive requirements. Both A1 and A2 are configured to apply the largest possible differential signal to the transformer. The largest signal available on a single 5 V supply is approximately 4.0 V p-p into a 600 Ω transmission system. Amplifier A3 is configured as a difference amplifier to extract the receive information from the transmission line for amplification by A4. A3 also prevents the transmit signal from interfering with the receive signal. The gain of A4 can be adjusted in the same manner as A1 to meet the modem's input signal requirements. Standard resistor values permit the use of SIP (single in-line package) format resistor arrays. Couple this with the OP462 14-lead SOIC or TSSOP package and this circuit offers a compact solution.
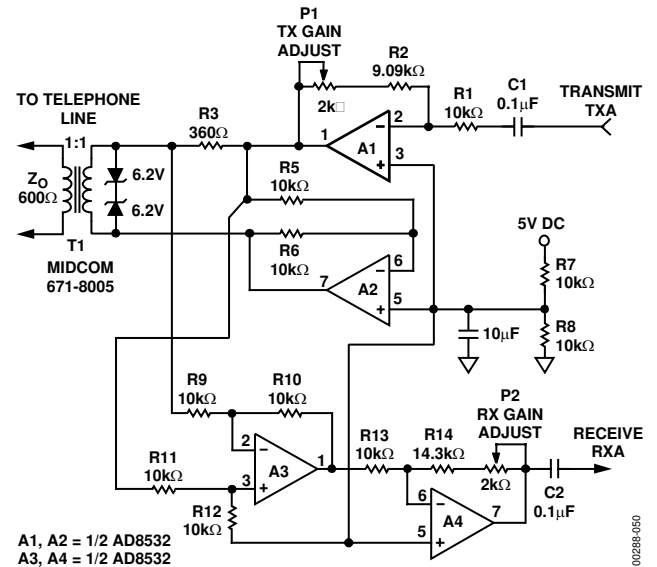
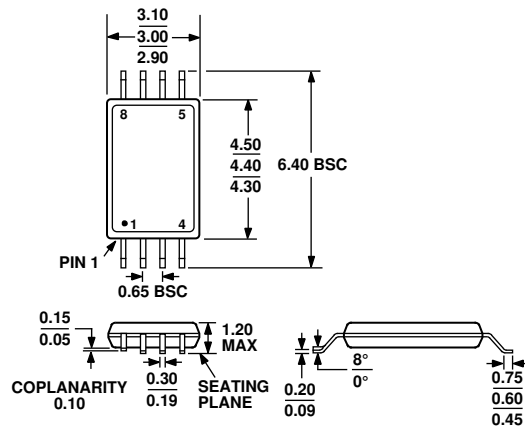*Figure 47. Single-Supply Direct Access Arrangement for Modems*

OUTLINE DIMENSIONS
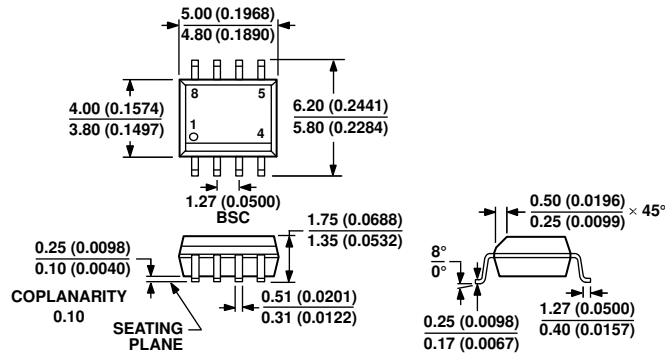
COMPLIANT TO JEDEC STANDARDS MS-012-AA
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS
(IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR
REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

012407-A

Figure 48. 8-Lead Standard Small Outline Package [SOIC_N] Narrow Body
S-Suffix (R-8)
Dimensions shown in millimeters and (inches)

COMPLIANT TO JEDEC STANDARDS MO-153-AA

Figure 49. 8-Lead Thin Shrink Small Outline Package [TSSOP]
(RU-8)
Dimensions shown in millimeters

COMPLIANT TO JEDEC STANDARDS MO-153-AB-1

061908-A

Figure 50. 14-Lead Thin Shrink Small Outline Package [TSSOP]
(RU-14)
Dimensions shown in millimeters
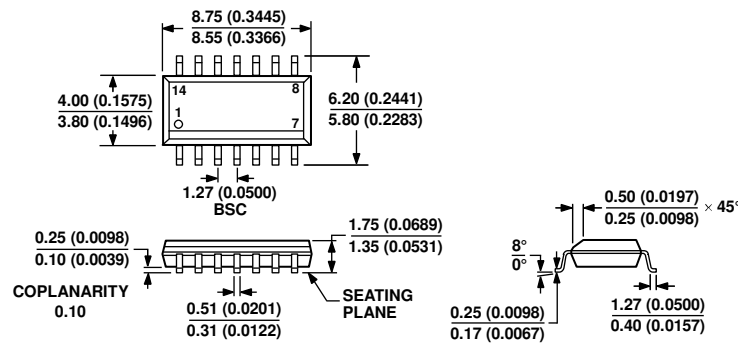
COMPLIANT TO JEDEC STANDARDS MS-012-AB
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS
(IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR
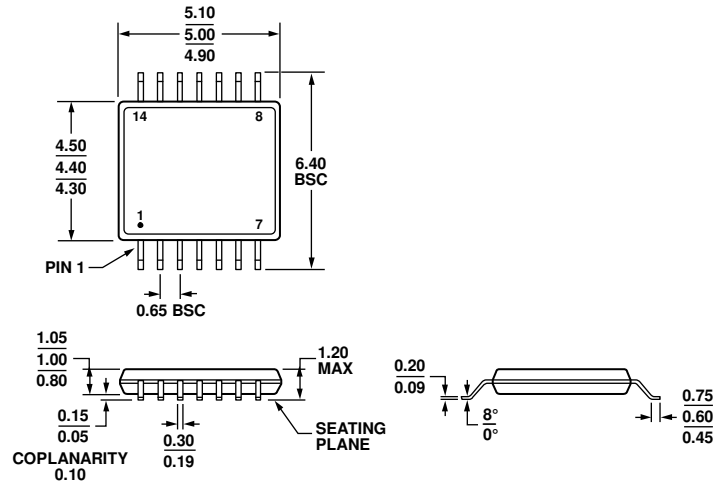REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

060606-A

Figure 51. 14-Lead Standard Small Outline Package [SOIC_N] Narrow Body
S-Suffix (R-14)
Dimensions shown in millimeters and (inches)

ORDERING GUIDE

Model[1]	Temperature Range	Package Description	Package Option
OP162GSZ	−40°C to +125°C	8-Lead SOIC_N	S-Suffix (R-8)
OP162GSZ-REEL	−40°C to +125°C	8-Lead SOIC_N	S-Suffix (R-8)
OP162GSZ-REEL7	−40°C to +125°C	8-Lead SOIC_N	S-Suffix (R-8)
OP262DRUZ-REEL	−40°C to +125°C	8-Lead TSSOP	RU-8
OP262GS	−40°C to +125°C	8-Lead SOIC_N	S-Suffix (R-8)
OP262GS-REEL	−40°C to +125°C	8-Lead SOIC_N	S-Suffix (R-8)
OP262GS-REEL7	−40°C to +125°C	8-Lead SOIC_	S-Suffix (R-8)
OP262GSZ	−40°C to +125°C	8-Lead SOIC_N	S-Suffix (R-8)
OP262GSZ-REEL	−40°C to +125°C	8-Lead SOIC_N	S-Suffix (R-8)
OP262GSZ-REEL7	−40°C to +125°C	8-Lead SOIC_N	S-Suffix (R-8)
OP262HRU-REEL	−40°C to +125°C	8-Lead TSSOP	RU-8
OP262HRUZ	−40°C to +125°C	8-Lead TSSOP	RU-8
OP262HRUZ-REEL	−40°C to +125°C	8-Lead TSSOP	RU-8
OP462GS	−40°C to +125°C	14-Lead SOIC_	S-Suffix (R-14)
OP462GS-REEL	−40°C to +125°C	14-Lead SOIC_N	S-Suffix (R-14)
OP462GS-REEL7	−40°C to +125°C	14-Lead SOIC_N	S-Suffix (R-14)
OP462GSZ	−40°C to +125°C	14-Lead SOIC_N	S-Suffix (R-14)
OP462GSZ-REEL	−40°C to +125°C	14-Lead SOIC_N	S-Suffix (R-14)
OP462GSZ-REEL7	−40°C to +125°C	14-Lead SOIC_N	S-Suffix (R-14)
OP462HRU-REEL	−40°C to +125°C	14-Lead TSSOP	RU-14
OP462HRUZ-REEL	−40°C to +125°C	14-Lead TSSOP	RU-14

[1] Z = RoHS Compliant Part.

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